ANALOG
DEVICESHigh Speed, 3.3 V/5 V Quad 2:1 Mux/Demux
(4-Bit, 1 of 2) Bus Switch

ADG3257

FEATURES

100 ps propagation delay through the switch 2 Ω switches connect inputs to outputs Data rates up to 933 Mbps Single 3.3 V/5 V supply operation Level translation operation Ultralow quiescent supply current (1 nA typical) 3.5 ns switching Switches remain in the off state when power is off Standard 3257 type pinout

APPLICATIONS

Bus switching Bus isolation Level translation Memory switching/interleaving

GENERAL DESCRIPTION

The ADG3257 is a CMOS bus switch comprised of four 2:1 multiplexers/demultiplexers with high impedance outputs. The device is manufactured on a CMOS process. This provides low power dissipation yet high switching speed and very low on resistance, allowing the inputs to be connected to the outputs without adding propagation delay or generating additional ground bounce noise.

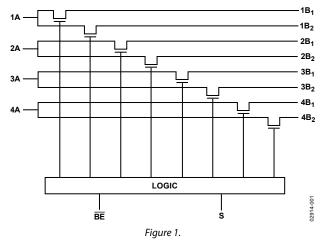
The ADG3257 operates from a single 3.3 V/5 V supply. The control logic for each switch is shown in Table 1. These switches are bidirectional when on. In the off state, signal levels are blocked up to the supplies. When the power supply is off, the switches remain in the off state, isolating Port A and Port B.

This bus switch is suited to both switching and level translation applications. It can be used in applications requiring level translation from 3.3 V to 2.5 V when powered from 3.3 V. Additionally, with a diode connected in series with 5 V V_{DD} , the ADG3257 may also be used in applications requiring 5 V to 3.3 V level translation.

Table 1. Truth Table

BE	S	Function
Н	Х	Disable
L	L	$A = B_1$
L	Н	$A = B_2$

FUNCTIONAL BLOCK DIAGRAM



PRODUCT HIGHLIGHTS

- 1. 0.1 ns propagation delay through switch.
- 2. 2 Ω switches connect inputs to outputs.
- 3. Bidirectional operation.
- 4. Ultralow power dissipation.
- 5. 16-lead QSOP package.

Rev. E

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REVISION HISTORY

03/08—Rev. D to Rev. E	
Updated FormatUn	iversal
Changes to Features	1
Changes to General Description	1
Changes to Absolute Maximum Ratings	5
Changes to Pin Configuration and Function Descriptions	6
Changes to Test Circuits	9
Changes to Ordering Guide	11
11/04—Rev. C to Rev. D	
Changes to Specifications	2
Changes to Ordering Guide	4
04/03—Rev. A to Rev. B	
Updated Outline Dimensions	8
06/02—Rev. 0 to Rev. A	
Edits to Features	1

SPECIFICATIONS

 V_{CC} = 5.0 V ± 10%, GND = 0 V. All specifications T_{MIN} to T_{MAX} , unless otherwise noted.

Table 2.

				B Versio	n	
Parameter ¹	Symbol	Conditions ²	Min	Тур³	Max	Unit
DC ELECTRICAL CHARACTERISTICS						
Input High Voltage	VINH		2.4			V
Input Low Voltage	VINL		-0.3		+0.8	V
Input Leakage Current	lı –	$0 \le V_{IN} \le 5.5 V$		±0.01	±1	μA
Off State Leakage Current	loz	$0 \le A, B \le V_{CC}$		±0.01	±1	μA
On State Leakage Current	loz	$0 \le A, B \le V_{CC}$		±0.01	±1	μA
Maximum Pass Voltage ⁴	VP	$V_{IN} = V_{CC} = 5 V$, $I_0 = -5 \mu A$	3.9	4.2	4.4	V
CAPACITANCE ⁴						
A Port Off Capacitance	C _A OFF	f = 1 MHz		7		рF
B Port Off Capacitance	C _B OFF	f = 1 MHz		5		рF
A, B Port On Capacitance	C _A , C _B ON	f = 1 MHz		11		рF
Control Input Capacitance	CIN	f = 1 MHz		4		рF
SWITCHING CHARACTERISTICS ⁴						
Propagation Delay A to B or B to A, t_{PD}	t _{PHL} , t _{PLH} ⁵	$V_A = 0 V, C_L = 50 pF$			0.10	ns
Propagation Delay Matching ⁶		$V_A = 0 V, C_L = 50 pF$		0.0075	0.035	ns
Bus Enable Time BE to A or B	t _{PZH} , t _{PZL}	$C_L = 50 \text{ pF}, R_L = 500 \Omega$	1	5	7.5	ns
Bus Disable Time BE to A or B	tphz, tplz	$C_L = 50 \text{ pF, } R_L = 500 \Omega$	1	3.5	7	ns
Bus Select Time S to A or B						
Enable	t _{SEL_EN}	$C_L = 50 \text{ pF, } R_L = 500 \Omega$		8	12	ns
Disable	t _{SEL_DIS}	$C_L = 50 \text{ pF}, R_L = 500 \Omega$		5	8	ns
Maximum Data Rate		$V_A = 2 V p - p$		933		Mbp
DIGITAL SWITCH						
On Resistance	Ron	$V_A = 0 V$				
		$I_0 = 48 \text{ mA}$, 15 mA, 8 mA, $T_A = 25^{\circ}\text{C}$		2	4	Ω
		l _o = 48 mA, 15 mA, 8 mA			5	Ω
		$V_A = 2.4 V$				
		$I_0 = 48 \text{ mA}, 15 \text{ mA}, 8 \text{ mA}, T_A = 25^{\circ}\text{C}$		3	6	Ω
		l _o = 48 mA, 15 mA, 8 mA			7	Ω
On-Resistance Matching	ΔR_{ON}	$V_A = 0 V$, $I_0 = 48 mA$, 15 mA, 8 mA		0.15		Ω
POWER REQUIREMENTS						
Vcc			3.0		5.5	V
Quiescent Power Supply Current	lcc	Digital inputs = $0 V$ or V_{CC}		0.001	1	μA
Increase in I _{cc} per Input ^{4, 7}	Δlcc	$V_{cc} = 5.5$ V, one input at 3.0 V; others at V_{cc} or GND			200	μA

¹ Temperature range is: Version B: -40°C to +85°C.

² See Test Circuits section.

 $^{\rm 3}$ All typical values are at T_A = 25°C, unless otherwise noted.

⁴ Guaranteed by design, not subject to production test.

⁵ The digital switch contributes no propagation delay other than the RC delay of the typical R_{oN} of the switch and the load capacitance when driven by an ideal voltage source. Because the time constant is much smaller than the rise/fall times of typical driving signals, it adds very little propagation delay to the system. Propagation delay of the digital switch, when used in a system, is determined by the driving circuit on the driving side of the switch and its interaction with the load on the driven side.
⁶ Propagation delay matching between channels is calculated from on-resistance matching of worst-case channel combinations and load capacitance.

⁷ This current applies to the control pins only and represents the current required to switch internal capacitance at the specified frequency. The A and B ports contribute no significant ac or dc currents as they transition.

 V_{CC} = 3.3 V \pm 10%, GND = 0 V. All specifications T_{MIN} to T_{MAX} unless otherwise noted.

Table 3.

			B Version				
Parameter ¹	Symbol	Conditions ²	Min	Тур³	Мах	Unit	
DC ELECTRICAL CHARACTERISTICS							
Input High Voltage	VINH		2.0			V	
Input Low Voltage	VINL		-0.3		+0.8	V	
Input Leakage Current	lı –	$0 \le V_{IN} \le 3.6 V$		±0.01	±1	μA	
Off State Leakage Current	loz	$0 \le A, B \le V_{CC}$		±0.01	±1	μA	
On State Leakage Current	loz	$0 \le A, B \le V_{CC}$		±0.01	±1	μΑ	
Maximum Pass Voltage ⁴	VP	$V_{IN} = V_{CC} = 3.3 \text{ V}, I_0 = -5 \mu\text{A}$	2.3	2.6	2.8	V	
CAPACITANCE ^₄							
A Port Off Capacitance	C _A OFF	f = 1 MHz		7		рF	
B Port Off Capacitance	C _B OFF	f = 1 MHz		5		рF	
A, B Port On Capacitance	C _A , C _B ON	f = 1 MHz		11		рF	
Control Input Capacitance	CIN	f = 1 MHz		4		рF	
SWITCHING CHARACTERISTICS ⁴							
Propagation Delay A to B or B to A, t_{PD}	tphl, tplh ⁵	$V_A = 0 V, C_L = 50 pF$			0.10	ns	
Propagation Delay Matching ⁶		$V_A = 0 V, C_L = 50 pF$		0.01	0.04	ns	
Bus Enable Time BE to A or B	tpzh, tpzl	$C_L = 50 \text{ pF}, R_L = 500 \Omega$	1	5.5	9	ns	
Bus Disable Time BE to A or B	tphz, tplz	$C_L = 50 \text{ pF}, R_L = 500 \Omega$	1	4.5	8.5	ns	
Bus Select Time S to A or B							
Enable	tsel_en	$C_L = 50 \text{ pF}, R_L = 500 \Omega$		8	12	ns	
Disable	t _{SEL_DIS}	$C_L = 50 \text{ pF}, R_L = 500 \Omega$		6	9	ns	
Maximum Data Rate		$V_A = 2 V p - p$		933		Mbps	
DIGITAL SWITCH							
On Resistance	Ron	$V_A = 0 V$, $I_O = 15 mA$, 8 mA, $T_A = 25^{\circ}C$		2	4	Ω	
		V_{A} = 0 V, I_{o} = 15 mA, 8 mA			5	Ω	
		$V_A = 1 V$, $I_0 = 15 mA$, 8 mA, $T_A = 25^{\circ}C$		4	7	Ω	
		$V_A = 1 V$, $I_o = 15 mA$, 8 mA			8	Ω	
On-Resistance Matching	ΔRon	$V_A = 0 V$, $I_0 = 15 mA$, 8 mA		0.2		Ω	
POWER REQUIREMENTS							
Vcc			3.0		5.5	V	
Quiescent Power Supply Current	Icc	Digital inputs = $0 V \text{ or } V_{CC}$		0.001	1	μA	
Increase in I _{CC} per Input ^{4, 7}	Δlcc	$V_{cc} = 3.3$ V, one input at 3.0 V; others at V_{cc} or GND			200	μA	

¹ Temperature range is: Version B: -40°C to +85°C.

² See Test Circuits section.

 3 All typical values are at T_A = 25 °C, unless otherwise noted.

⁴ Guaranteed by design, not subject to production test.

⁵ The digital switch contributes no propagation delay other than the RC delay of the typical R_{ON} of the switch and the load capacitance when driven by an ideal voltage source. Because the time constant is much smaller than the rise/fall times of typical driving signals, it adds very little propagation delay to the system. Propagation delay of the digital switch, when used in a system, is determined by the driving circuit on the driving side of the switch and its interaction with the load on the driven side.
⁶ Propagation delay matching between channels is calculated from on-resistance matching of worst-case channel combinations and load capacitance.

⁷ This current applies to the control pins only and represents the current required to switch internal capacitance at the specified frequency. The A and B ports contribute no significant ac or dc currents as they transition.

ABSOLUTE MAXIMUM RATINGS

 $T_A = 25^{\circ}C$, unless otherwise noted.

Table 4.

Parameter	Rating		
V _{cc} to GND	–0.3 V to +6 V		
Digital Inputs to GND	–0.3 V to +6 V		
DC Input Voltage	–0.3 V to +6 V		
DC Output Current	100 mA		
Operating Temperature Range			
Industrial (B Version)	-40°C to +85°C		
Storage Temperature Range	−65°C to +150°C		
Junction Temperature	150°C		
QSOP Package			
θ _{JA} Thermal Impedance	149.97°C/W		
Lead Soldering			
Lead Temperature, Soldering (10 sec)	300°C		
IR Reflow, Peak Temperature (<20 sec)	220°C		
Soldering (Pb-Free)			
Reflow, Peak Temperature	260(+0/-5)°C		
Time at Peak Temperature	20 sec to 40 sec		

Stresses above those listed under Absolute Maximum Ratings may cause permanent damage to the device. This is a stress rating only; functional operation of the device at these or any other conditions above those indicated in the operational section of this specification is not implied. Exposure to absolute maximum rating conditions for extended periods may affect device reliability.

ESD CAUTION



ESD (electrostatic discharge) sensitive device. Charged devices and circuit boards can discharge without detection. Although this product features patented or proprietary protection circuitry, damage may occur on devices subjected to high energy ESD. Therefore, proper ESD precautions should be taken to avoid performance degradation or loss of functionality.

PIN CONFIGURATION AND FUNCTION DESCRIPTIONS

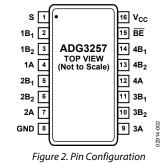


Table 5. Pin Function Descriptions

Pin No.	Mnemonic	Description		
1	S	Port Select.		
2, 3, 5, 6, 10, 11, 13, 14	1B ₁ , 1B ₂ , 2B ₁ , 2B ₂ , 3B ₂ , 3B ₁ , 4B ₂ , 4B ₁	Port B, Inputs or Outputs.		
4, 7, 9, 12	1A, 2A, 3A, 4A	Port A, Inputs or Outputs.		
8	GND	Negative Power Supply.		
15	BE	Output Enable (Active Low).		
16	Vcc	Positive Power Supply.		

TYPICAL PERFORMANCE CHARACTERISTICS

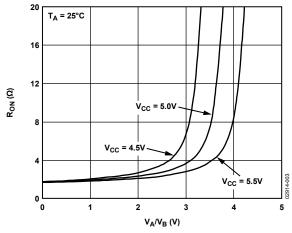
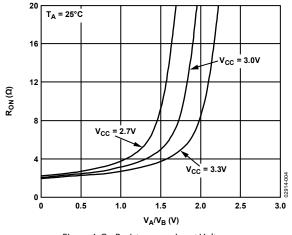
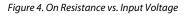


Figure 3. On Resistance vs. Input Voltage





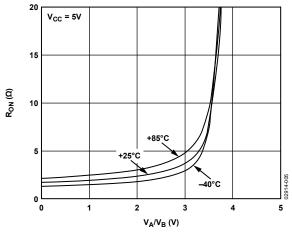


Figure 5. On Resistance vs. Input Voltage for Different Temperatures

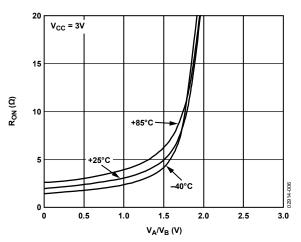
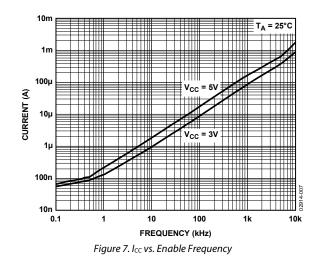
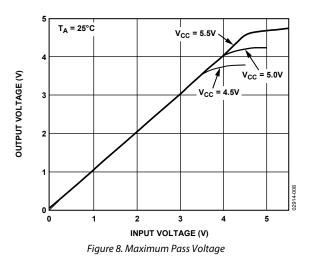
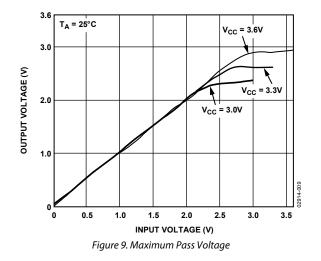


Figure 6. On Resistance vs. Input Voltage for Different Temperatures







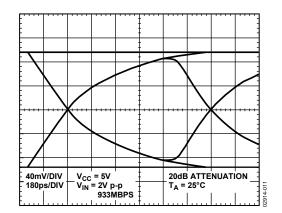
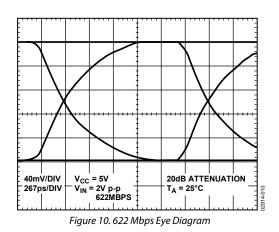
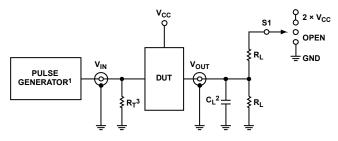


Figure 11.933 Mbps Eye Diagram



TEST CIRCUITS



 1 PULSE GENERATOR FOR ALL PULSES: t_F <2.5ns, t_R <2.5ns, 2C_L = INCLUDES BOARD, STRAY, AND LOAD CAPACITANCES. 3R_T IS THE TERMINATION RESISTOR; SHOULD BE EQUAL TO Z_{OUT} OF THE PULSE GENERATOR.

Figure 12. Load Circuit

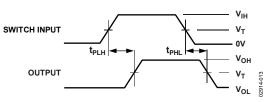


Figure 13. Propagation Delay

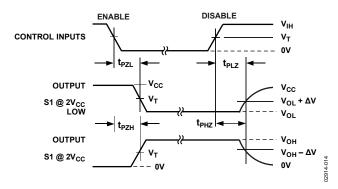


Figure 14. Select, Enable, and Disable Times

Table 6. Switch S1 Condition

Test	S1
tplh, tphl	Open
tplz, tpzl	2 × V _{CC}
tphz, tpzh	GND
t _{SEL}	Open

Table 7. Test Conditions

02914-012

Symbol	$V_{cc} = 5 V \pm 10\%$	$V_{cc} = 3.3 V \pm 10\%$	Unit	
R∟	500	500	Ω	
ΔV	300	300	mV	
CL	50	50	pF	

APPLICATIONS INFORMATION

MIXED VOLTAGE OPERATION, LEVEL TRANSLATION

Bus switches can be used to provide a solution for mixed voltage systems where interfacing bidirectionally between 5 V and 3.3 V devices is required. To interface between 5 V and 3.3 V buses, an external diode is placed in series with the 5 V power supply as shown in Figure 15.

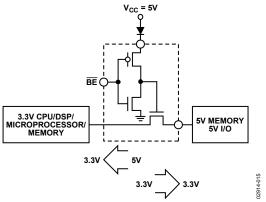


Figure 15. Level Translation Between 5 V and 3.3 V Devices

The diode drops the internal gate voltage down to 4.3 V. The bus switch limits the voltage present on the output to

 V_{CC} – External Diode Drop = V_{TH}

Therefore, assuming a diode drop of 0.7 V and a $V_{\rm TH}$ of 1 V, the output voltage is limited to 3.3 V with a logic high.

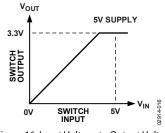


Figure 16. Input Voltage to Output Voltage

Similarly, the device could be used to translate bidirectionally between 3.3 V to 2.5 V systems. In this case, there is no need for an external diode. The internal V_{TH} drop is 1 V, so with a V_{CC} = 3.3 V the bus switch limits the output voltage to

 $V_{CC} - 1 \text{ V} = 2.3 \text{ V}$

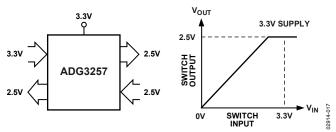


Figure 17. 3.3 V to 2.5 V Level Translation Using the ADG3257 Bus Switch

MEMORY SWITCHING

This quad bus switch may be used to allow switching between different memory banks, thus allowing additional memory and decreasing capacitive loading. Figure 18 illustrates the ADG3257 in such an application.

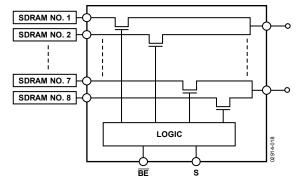
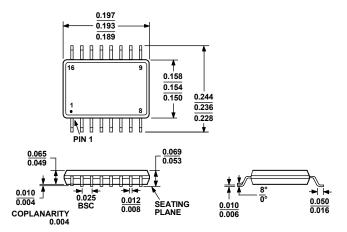


Figure 18. Allows Additional Memory Modules Without Added Drive or Delay

OUTLINE DIMENSIONS



COMPLIANT TO JEDEC STANDARDS MO-137-AB

Figure 19. 16-Lead Shrink Small Outline Package [QSOP] (RQ-16) Dimensions shown in inches

ORDERING GUIDE

Model	Temperature Range	Package Description	Package Option
ADG3257BRQ	–40°C to +85°C	16-Lead Shrink Small Outline Package [QSOP]	RQ-16
ADG3257BRQ-REEL	–40°C to +85°C	16-Lead Shrink Small Outline Package [QSOP]	RQ-16
ADG3257BRQ-REEL7	–40°C to +85°C	16-Lead Shrink Small Outline Package [QSOP]	RQ-16
ADG3257BRQZ ¹	–40°C to +85°C	16-Lead Shrink Small Outline Package [QSOP]	RQ-16
ADG3257BRQZ-REEL ¹	–40°C to +85°C	16-Lead Shrink Small Outline Package [QSOP]	RQ-16
ADG3257BRQZ-REEL71	–40°C to +85°C	16-Lead Shrink Small Outline Package [QSOP]	RQ-16

¹ Z = RoHS Compliant Part.

NOTES

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